Drafts
Pending
Active

Failed
Saved
- (24) memory and test53 and defect53 and repair53 and (alternat53 ne...
- (812) memory and test53 and defect53 and repair53
- (0) (memory and test53 and defect53 and repair53) and ((temp53 near...
- (641) (temp53 near3 (mtor53 buffer)) with data
- (0) (memory and test53 and detect53 and repair53) and (temp53 wit...
- (291) (memory and test53 and defect53 and repair53) and (test53 wit...
- (24) ((memory and test53 and defect53 and repair53) and (test53 wit...
- (21) ((memory and test53 and defect53 and repair53) and (test53 wit...
- (26) "L24" and (mov53 near3 data)
- (2) ((memory and test53 and defect53 and repair53) and (test53 with...
- (1527) detect53 near4 defect53 near3 (cell transistor)
- (400) test with (detect53 near4 defect53 near3 (cell transistor))
- (509) test53 with (detect53 near4 defect53 near3 (cell transistor))
- (20) (test53 with (detect53 near4 defect53 near3 (cell transistor))
- (20) (test53 with (detect53 near4 defect93 near3 (cell transistor))
- (113) (memory and test53 and defect53 and repair53) and ((buffer la...
- (2625656) 1
- (11) ((memory and test53 and defect53 and repair53) and ((buffer la...
Favorites
Tagged (11)

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Default operator: OR

((memory and test53 and defect53 and repair53) and ((buffer latch register)
with (data information) with defect53) and controller and (data with
mtor53)) and (defect53 with temp97 with mtor53 with (data information))

	U	I	Document ID	Issue Date	Pages	Title	Current OR	Current XRef	Retrieval C	Inventor	F	C	D				
1			US 20020159118 A1	20021031	25	System of performing a repair analysis for a	365/200			Park, Sang Wook et al.	P						
2			US 20020015341 A1	20020207	22	Semiconductor memory device capable of recovering	365/200			Urakawa, Yukihiro	P						
3			US 20010227588 20010920	22	Semiconductor memory device capable of recovering	365/200			Urakawa, Yukihiro	P							
4			US 6505291 B1	20030107	41	Hard disk drive employing high speed distribution bus	711/168	709/200; 709/211;		Sherry, Raymond C.	P						
5			US 6462975 B2	20021008	21	Semiconductor memory device capable of recovering	365/200	365/225.7		Urakawa, Yukihiro	P		P				
6			US 6324106 B1	20011127	20	Semiconductor memory device capable of recovering	365/200	365/225.7		Urakawa, Yukihiro	P						
7			US 6246617 B1	20010612	21	Semiconductor memory device capable of recovering	365/200	365/200; 365/225.7		Urakawa, Yukihiro	P						

Ready